NSN 5962-01-309-3417

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View Online at https://aerobasegroup.com/nsn/5962-01-309-3417

Body	Length:

Between 0.930 inches and 0.970 inches

Body Width:

Between 0.245 inches and 0.310 inches

Body Height:

Between 0.140 inches and 0.175 inches

Maximum Power Dissipation Rating:

385.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

4920-01-187-4068 test system, aut

Features Provided:

Hermetically sealed and burn in and high speed and w/enable and static operation

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

18 input

Case Outline Source And Designator:

D-8 mil-m-38510

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Ram

Memory Capacity:

Unknown

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

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In	18	<i>(</i>)+	МЛО	201	ure:

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Demilitarization:

Yes - demil/mli

Fiig:

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